

## N-Channel 150-V (D-S) MOSFET

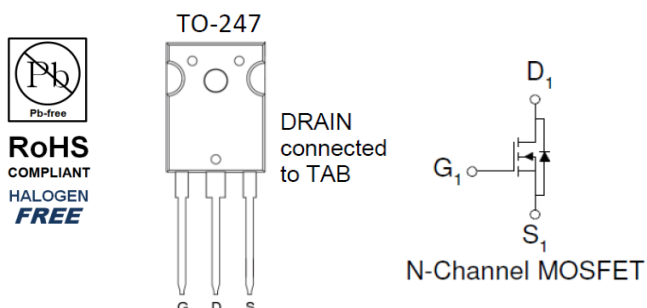
### Key Features:

- Low  $r_{DS(on)}$  trench technology
- Low thermal impedance
- Fast switching speed

### Typical Applications:

- LED Inverter Circuits
- Inrush Limiter and Hot Swap Circuits
- 48V-Input DC/DC Conversion Circuits

| PRODUCT SUMMARY |                            |                  |
|-----------------|----------------------------|------------------|
| $V_{DS}$ (V)    | $r_{DS(on)}$ (m $\Omega$ ) | $I_D$ (A)        |
| 150             | 4.5 @ $V_{GS} = 10V$       | 200 <sup>a</sup> |
|                 | 5.9 @ $V_{GS} = 6.5V$      |                  |



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

| Parameter   | Symbol                          | Limit      | Units            |
|---|---------------------------------|------------|------------------|
| Drain-Source Voltage                                      | $V_{DS}$                        | 150        | V                |
| Gate-Source Voltage                                       | $V_{GS}$                        | $\pm 20$   |                  |
| Continuous Drain Current <sup>a</sup>                     | $T_C=25^\circ\text{C}$<br>$I_D$ | 200        | A                |
| Pulsed Drain Current <sup>b</sup>                         | $I_{DM}$                        | 800        |                  |
| Continuous Source Current (Diode Conduction) <sup>a</sup> | $T_C=25^\circ\text{C}$<br>$I_S$ | 200        | A                |
| Avalanche Energy  | $L=0.5\text{mH}$<br>$E_{AS}$    | 600        | mJ               |
| Power Dissipation <sup>a</sup>                            | $T_C=25^\circ\text{C}$<br>$P_D$ | 500        | W                |
| Operating Junction and Storage Temperature Range          | $T_J, T_{stg}$                  | -55 to 175 | $^\circ\text{C}$ |

### THERMAL RESISTANCE RATINGS

| Parameter                                | Symbol          | Maximum | Units                     |
|--|-----------------|---------|---------------------------|
| Maximum Junction-to-Ambient <sup>c</sup> | $R_{\theta JA}$ | 40      | $^\circ\text{C}/\text{W}$ |
| Maximum Junction-to-Case                 | $R_{\theta JC}$ | 0.29    |                           |

### Notes

- Package Limited
- Pulse width limited by maximum junction temperature
- Surface Mounted on 1" x 1" FR4 Board.

## Electrical Characteristics

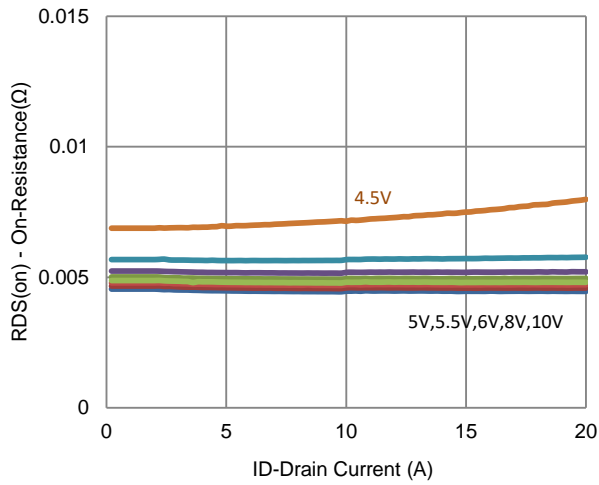
| Parameter                               | Symbol       | Test Conditions   | Min | Typ  | Max       | Unit |
|---|--------------|---|-----|------|-----------|------|
| <b>Static</b>                           |              |   |     |      |           |      |
| Gate-Source Threshold Voltage           | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250 \mu A$  | 1   |      |           | V    |
| Gate-Body Leakage                       | $I_{GSS}$    | $V_{DS} = 0 V, V_{GS} = \pm 20 V$   |     |      | $\pm 100$ | nA   |
| Zero Gate Voltage Drain Current         | $I_{DSS}$    | $V_{DS} = 120 V, V_{GS} = 0 V$  |     |      | 1         | uA   |
|   |              | $V_{DS} = 120 V, V_{GS} = 0 V, T_J = 55^\circ C$  |     |      | 10        |      |
| On-State Drain Current <sup>a</sup>     | $I_{D(on)}$  | $V_{DS} = 5 V, V_{GS} = 10 V$   | 50  |      |           | A    |
| Drain-Source On-Resistance <sup>a</sup> | $r_{DS(on)}$ | $V_{GS} = 10 V, I_D = 20 A$   |     |      | 4.5       | mΩ   |
|   |              | $V_{GS} = 6.5 V, I_D = 16 A$  |     |      | 5.9       |      |
| Forward Transconductance <sup>a</sup>   | $g_{fs}$     | $V_{DS} = 15 V, I_D = 20 A$   |     | 60   |           | S    |
| Diode Forward Voltage <sup>a</sup>      | $V_{SD}$     | $I_S = 20 A, V_{GS} = 0 V$  |     | 0.82 |           | V    |
| <b>Dynamic <sup>b</sup></b>             |              |   |     |      |           |      |
| Total Gate Charge                       | $Q_g$        | $V_{DS} = 75 V, V_{GS} = 6.5 V,$<br>$I_D = 20 A$  |     | 112  |           | nC   |
| Gate-Source Charge                      | $Q_{gs}$     |   |     | 35   |           |      |
| Gate-Drain Charge                       | $Q_{gd}$     |   |     | 38   |           |      |
| Turn-On Delay Time                      | $t_{d(on)}$  | $V_{DS} = 75 V, R_L = 3.8 \Omega,$<br>$I_D = 20 A,$<br>$V_{GEN} = 10 V, R_{GEN} = 6 \Omega$ |     | 88   |           | ns   |
| Rise Time                               | $t_r$        |   |     | 114  |           |      |
| Turn-Off Delay Time                     | $t_{d(off)}$ |   |     | 186  |           |      |
| Fall Time                               | $t_f$        |   |     | 145  |           |      |
| Input Capacitance                       | $C_{iss}$    | $V_{DS} = 50 V, V_{GS} = 0 V, f = 1 \text{ Mhz}$  |     | 8657 |           | pF   |
| Output Capacitance                      | $C_{oss}$    |   |     | 925  |           |      |
| Reverse Transfer Capacitance            | $C_{rss}$    |   |     | 565  |           |      |
| Body Diode Reverse Recovery Time        | $T_{rr}$     | $I_F = 20 A, di/dt = 100 A/\mu s$   |     | 144  |           | ns   |
| Body Diode Reverse Recovery Charge      | $Q_{rr}$     |   |     | 480  |           | nC   |

## Notes

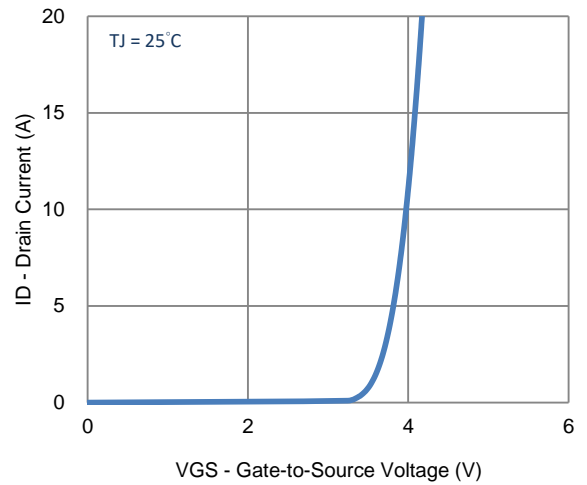
- Pulse test:  $PW \leq 300 \mu s$  duty cycle  $\leq 2\%$ .
- Guaranteed by design, not subject to production testing.

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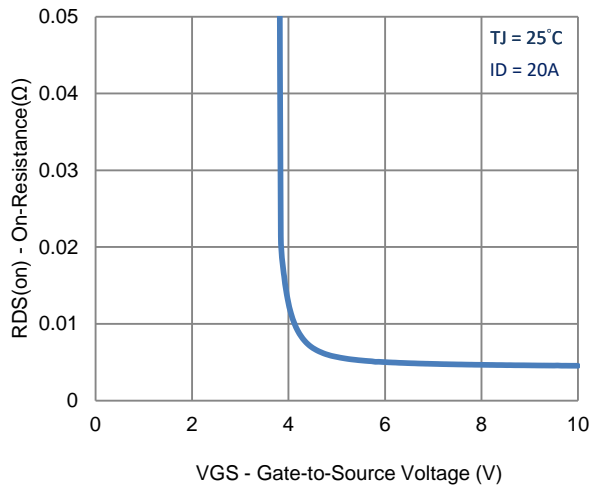
### Typical Electrical Characteristics



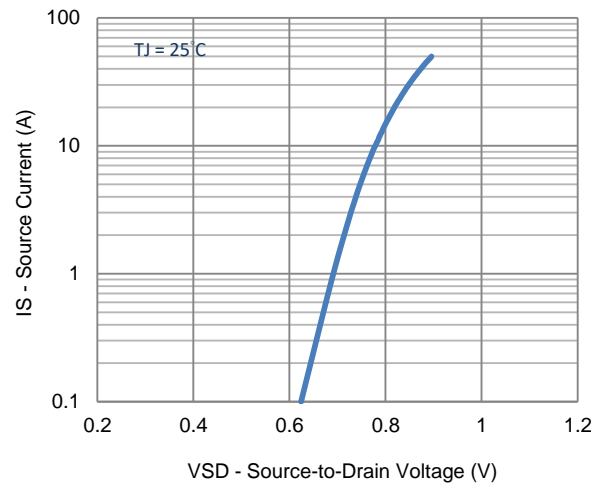
1. On-Resistance vs. Drain Current



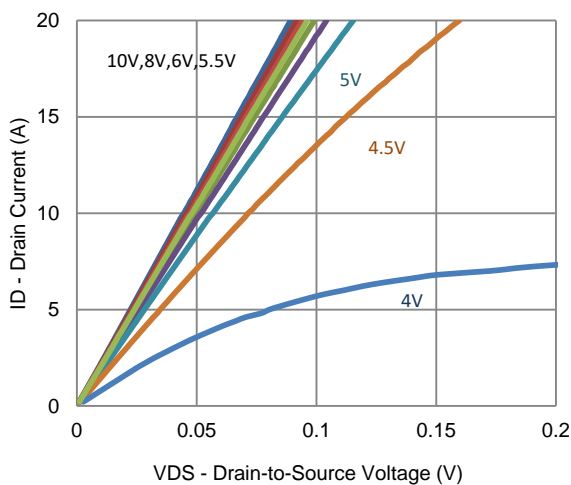
2. Transfer Characteristics



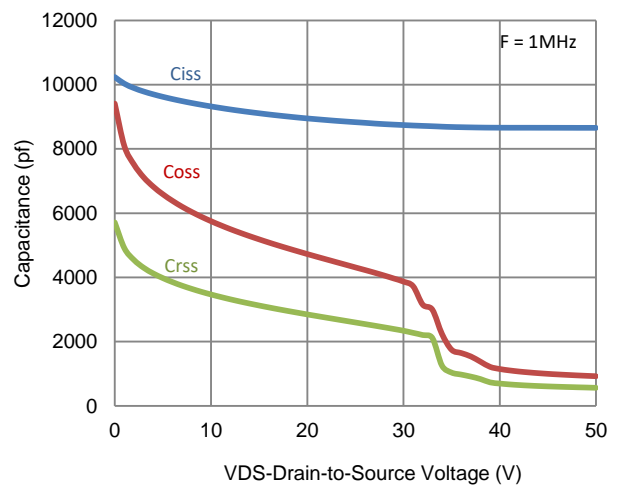
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage

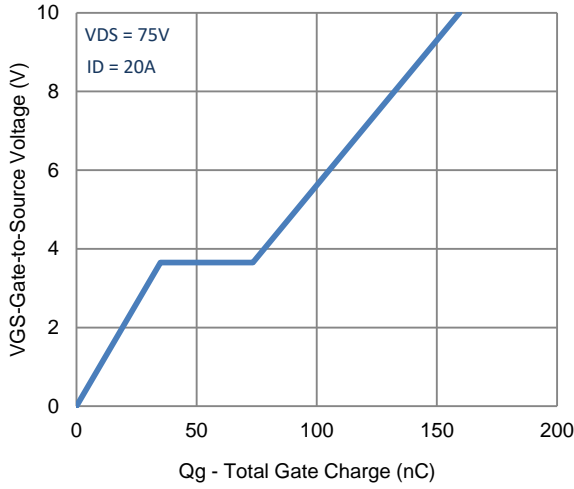


5. Output Characteristics

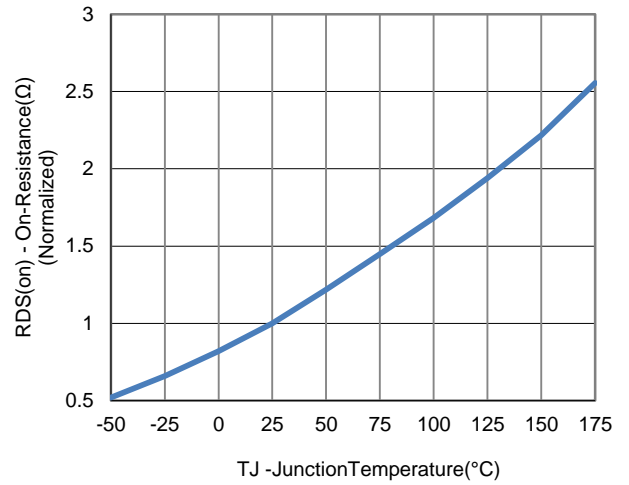


6. Capacitance

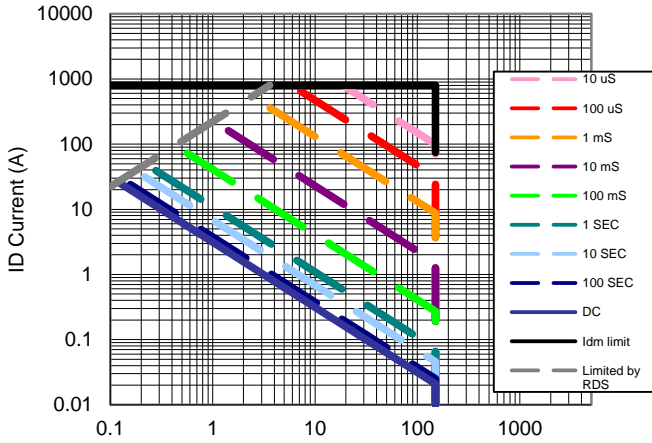
Typical Electrical Characteristics



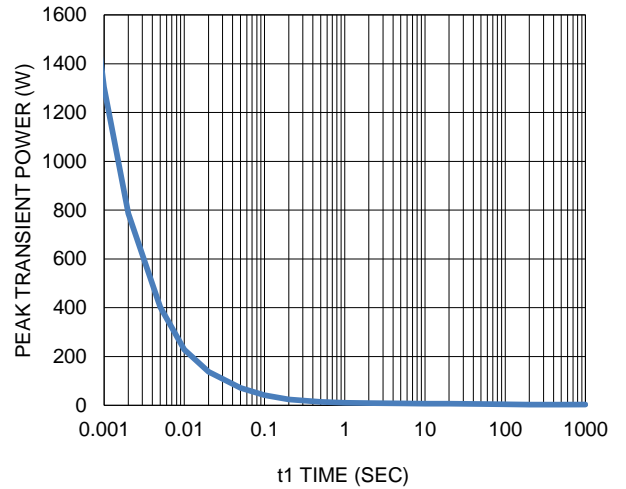
7. Gate Charge



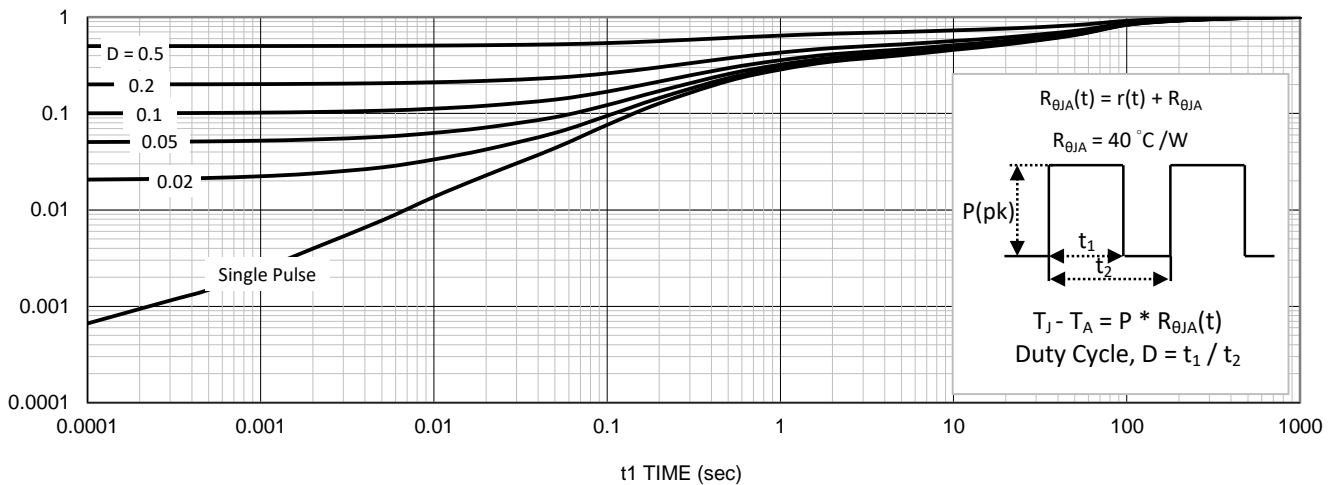
8. Normalized On-Resistance Vs Junction Temperature



9. Safe Operating Area

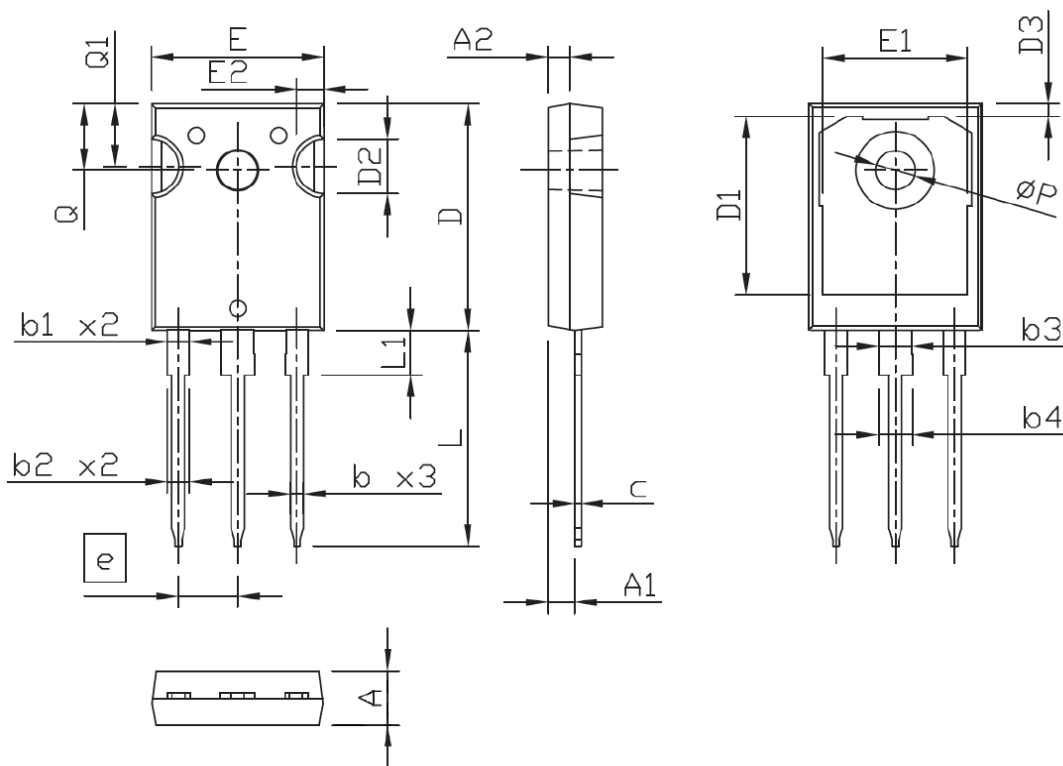


10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

Package Information



| SYMBOLS | DIMENSIONS IN MILLIMETERS |       |       |
|---------|---------------------------|-------|-------|
|         | MIN                       | NOM   | MAX   |
| A       | 4.90                      | 5.00  | 5.10  |
| A1      | 2.32                      | 2.42  | 2.52  |
| A2      | 1.90                      | 2.00  | 2.10  |
| b       | 1.17                      | 1.22  | 1.27  |
| b1      | 1.97                      | 2.02  | 2.07  |
| b2      | 2.00                      | 2.10  | 2.20  |
| b3      | 2.97                      | 3.02  | 3.07  |
| b4      | 3.00                      | 3.10  | 3.20  |
| c       | 0.59                      | 0.62  | 0.66  |
| D       | 20.90                     | 21.00 | 21.10 |
| D1      | 16.25                     | 16.55 | 16.85 |
| D2      | 5.00 TYP                  |       |       |
| D3      | 1.05                      | 1.20  | 1.35  |
| e       | 5.44 BSC                  |       |       |
| E       | 15.70                     | 15.80 | 15.90 |
| E1      | 13.06                     | 13.26 | 13.46 |
| E2      | 2.50 TYP                  |       |       |
| L       | 19.72                     | 19.92 | 20.12 |
| L1      | ---                       | ---   | 4.30  |
| Q       | 6.15 BSC                  |       |       |
| Q1      | 5.60                      | 5.80  | 6.00  |
| ØP      | 3.55                      | 3.60  | 3.65  |